

Table 4. Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (continued)

Characteristic	Symbol	Min	Typ	Max	Unit
Typical Performance (In Freescale Test Fixture, 50 ohm system) $V_{DD} = 28 \text{ Vdc}$, $I_{DQ} = 700 \text{ mA}$, 2110–2170 MHz Bandwidth					
P_{out} @ 1 dB Compression Point, CW	$P_{1\text{dB}}$	—	100	—	W
IMD Symmetry @ 36 W PEP, P_{out} where IMD Third Order Intermodulation $\leq 30 \text{ dBc}$ (Delta IMD Third Order Intermodulation between Upper and Lower Sidebands $> 2 \text{ dB}$)	IMD_{sym}	—	40	—	MHz
VBW Resonance Point (IMD Third Order Intermodulation Inflection Point)	VBW_{res}	—	50	—	MHz
Gain Flatness in 60 MHz Bandwidth @ $P_{out} = 24 \text{ W Avg.}$	G_F	—	0.4	—	dB
Gain Variation over Temperature (-30°C to $+80^\circ\text{C}$)	ΔG	—	0.011	—	dB/ $^\circ\text{C}$
Output Power Variation over Temperature (-30°C to $+80^\circ\text{C}$) (1)	$\Delta P_{1\text{dB}}$	—	0.005	—	dB/ $^\circ\text{C}$

1. Exceeds recommended operating conditions. See CW operation data in Maximum Ratings table.

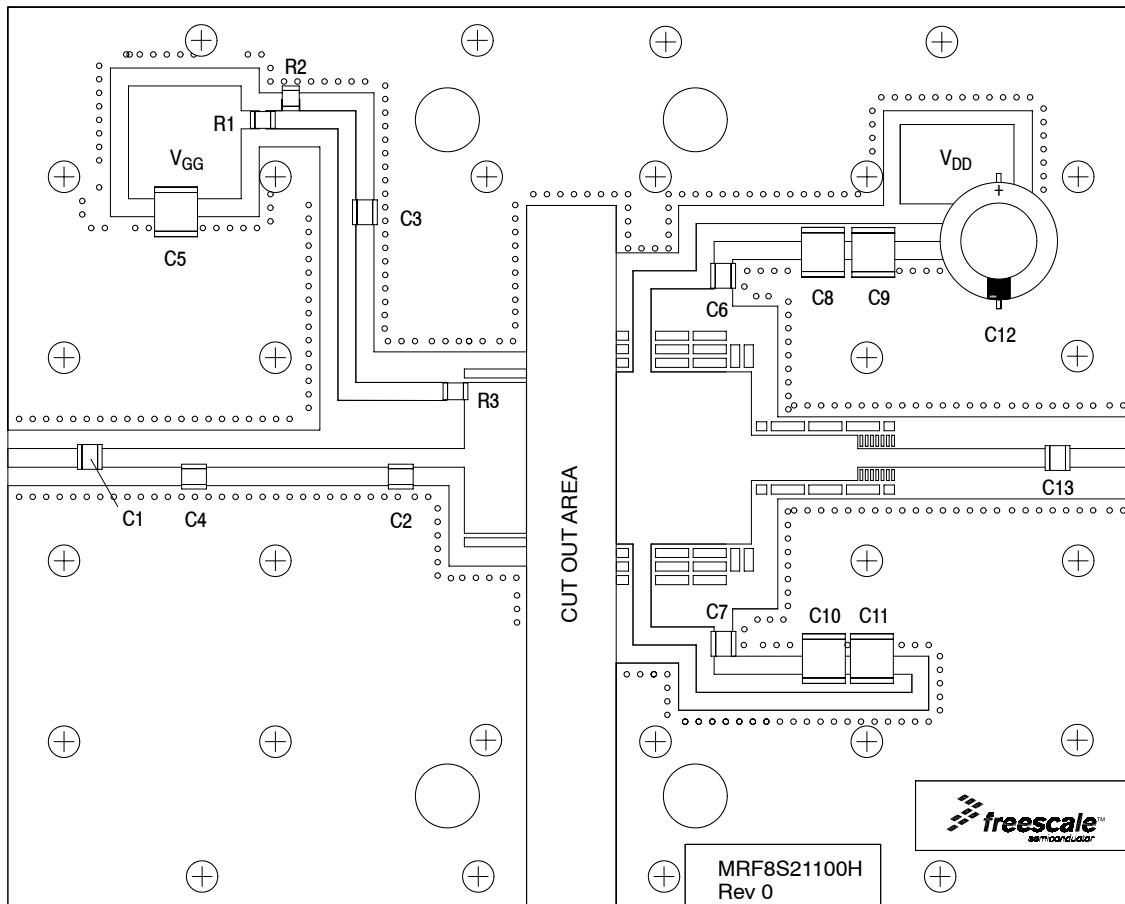


Figure 1. MRF8S21100HR3(HSR3) Test Circuit Component Layout

Table 5. MRF8S21100HR3(HSR3) Test Circuit Component Designations and Values

Part	Description	Part Number	Manufacturer
C1, C3, C6, C7	6.8 pF Chip Capacitors	ATC100B6R8CT500XT	ATC
C2	1.6 pF Chip Capacitor	ATC100B1R6BT500XT	ATC
C4	0.2 pF Chip Capacitor	ATC100B0R2BT500XT	ATC
C5, C8, C9, C10, C11	10 μ F, 50 V Tantalum Capacitors	293D106X9050E2TE3	Vishay
C12	220 μ F, 50 V Electrolytic Capacitor, Radial	227CKS050M	Illinois Capacitor
C13	5.6 pF Chip Capacitor	ATC100B5R6CT500XT	ATC
R1, R2	2 K Ω , 1/4 W Chip Resistors	CRCW12062K00FKEA	Vishay
R3	10 Ω , 1/4 W Chip Resistor	CRCW120610R0JNEA	Vishay
PCB	0.030", $\epsilon_r = 2.55$	AD255A	Arlon

TYPICAL CHARACTERISTICS

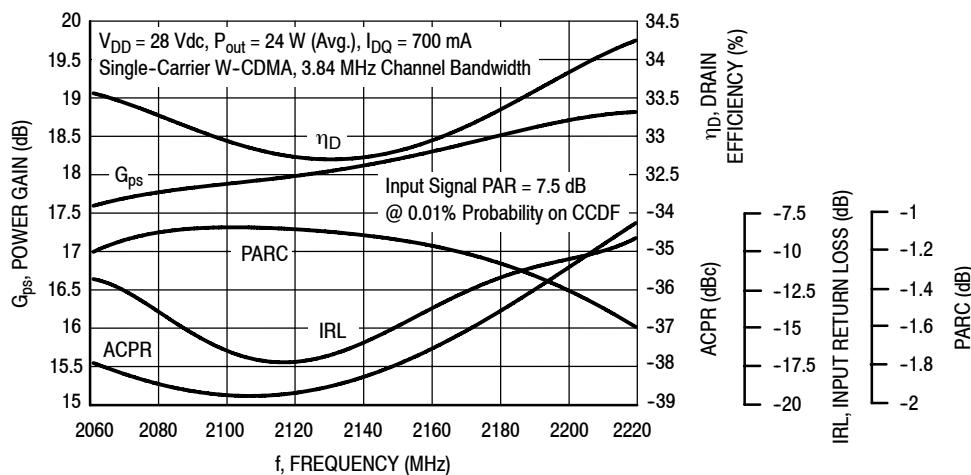


Figure 2. Output Peak-to-Average Ratio Compression (PARC) Broadband Performance @ $P_{out} = 24$ Watts Avg.

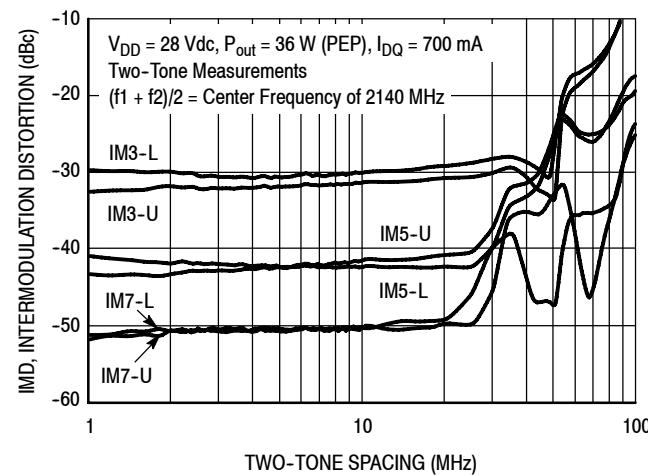


Figure 3. Intermodulation Distortion Products versus Two-Tone Spacing

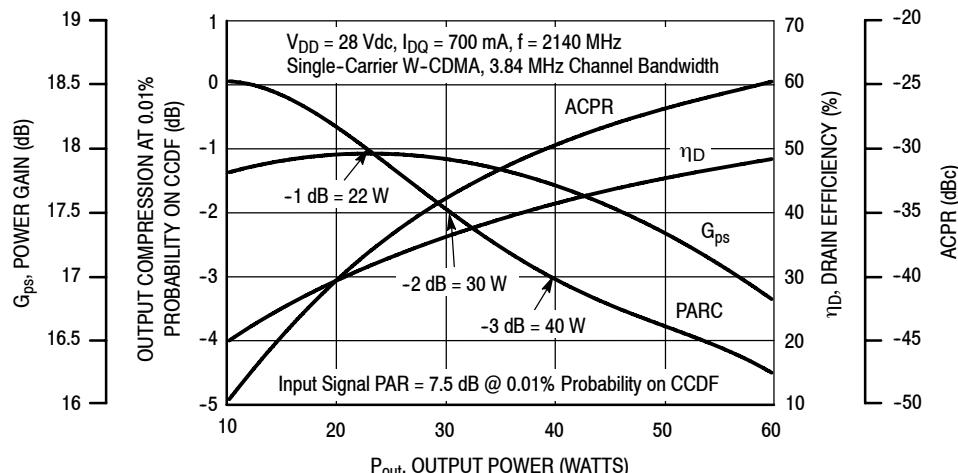


Figure 4. Output Peak-to-Average Ratio Compression (PARC) versus Output Power

TYPICAL CHARACTERISTICS

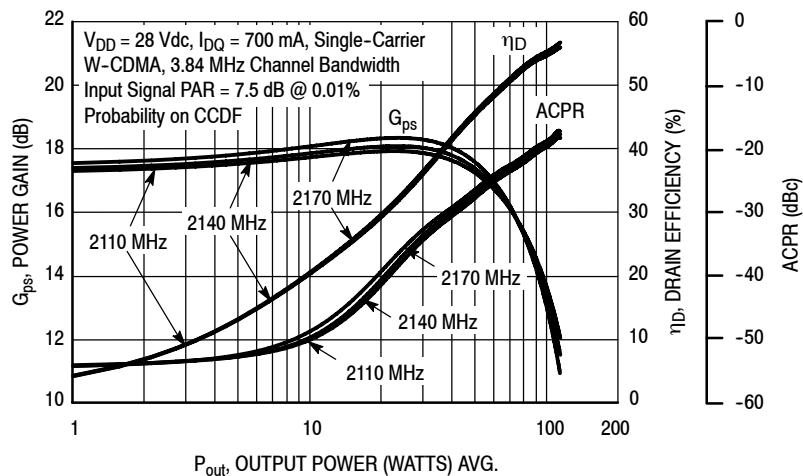


Figure 5. Single-Carrier W-CDMA Power Gain, Drain Efficiency and ACPR versus Output Power

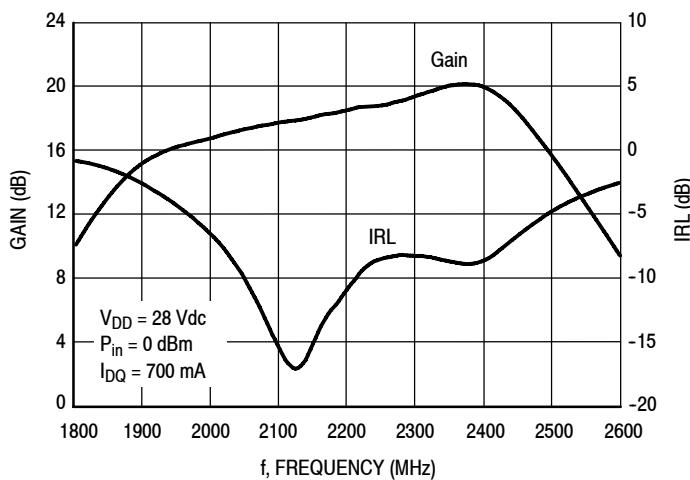


Figure 6. Broadband Frequency Response

W-CDMA TEST SIGNAL

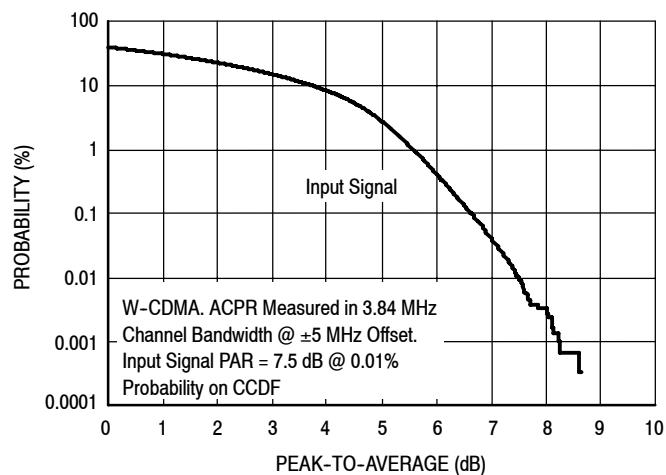


Figure 7. CCDF W-CDMA IQ Magnitude Clipping, Single-Carrier Test Signal

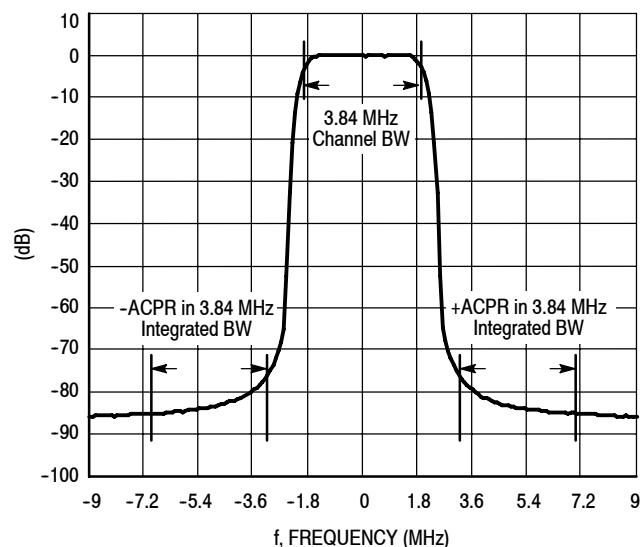


Figure 8. Single-Carrier W-CDMA Spectrum

$V_{DD} = 28$ Vdc, $I_{DQ} = 700$ mA, $P_{out} = 24$ W Avg.

f MHz	Z_{source} Ω	Z_{load} Ω
2060	4.41 - j6.05	3.03 - j3.64
2080	4.38 - j5.67	2.96 - j3.45
2100	4.33 - j5.29	2.89 - j3.26
2120	4.33 - j4.91	2.83 - j3.10
2140	4.33 - j4.54	2.75 - j2.94
2160	4.33 - j4.17	2.69 - j2.75
2180	4.31 - j3.80	2.62 - j2.50
2200	4.32 - j3.39	2.65 - j2.24
2220	4.35 - j2.99	2.67 - j2.04

Z_{source} = Test circuit impedance as measured from gate to ground.

Z_{load} = Test circuit impedance as measured from drain to ground.

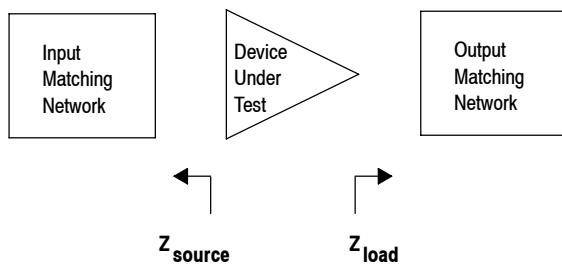
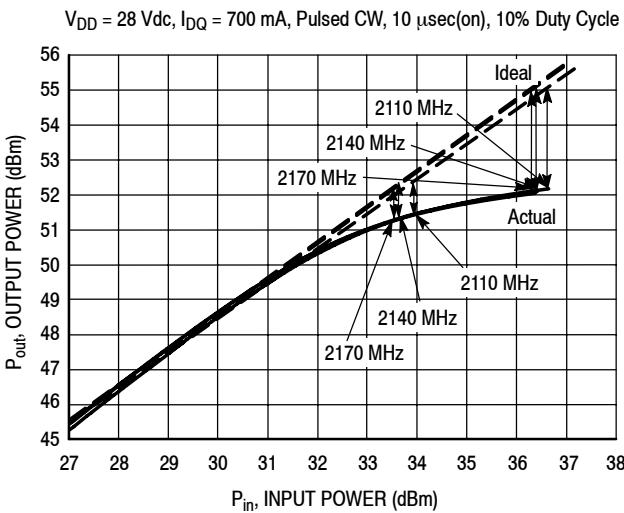


Figure 9. Series Equivalent Source and Load Impedance

ALTERNATIVE PEAK TUNE LOAD PULL CHARACTERISTICS



NOTE: Load Pull Test Fixture Tuned for Peak P1dB Output Power @ 28 V

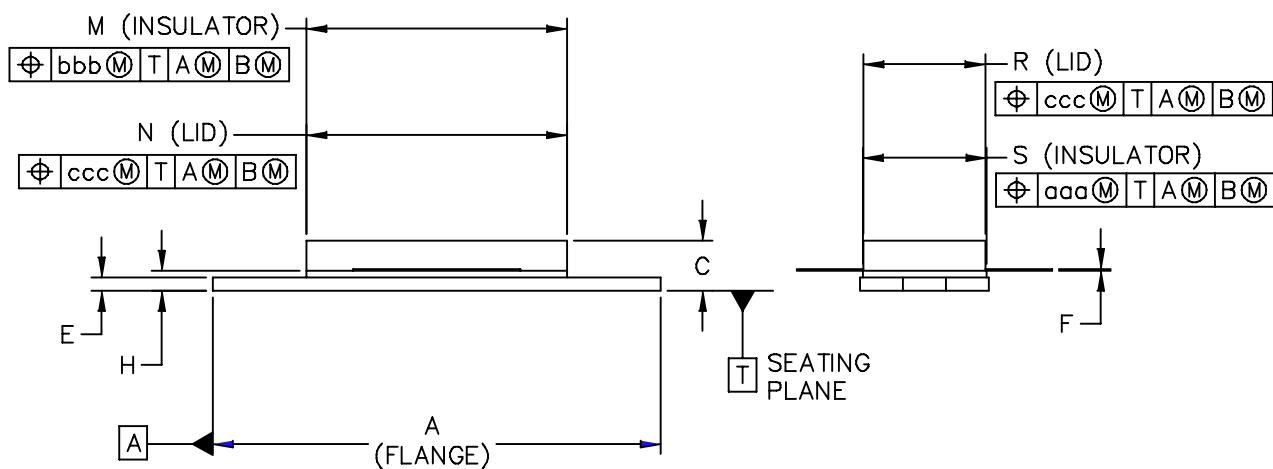
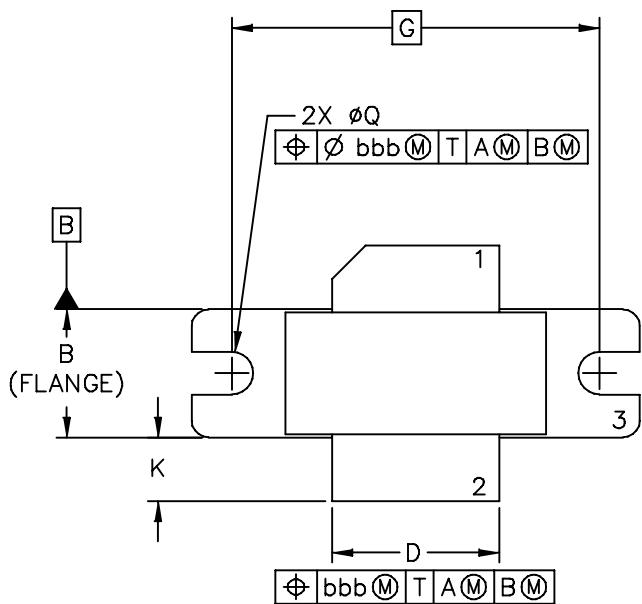
f (MHz)	P1dB		P3dB	
	Watts	dBm	Watts	dBm
2110	141	51.5	166	52.2
2140	141	51.5	162	52.1
2170	138	51.4	158	52.0

Test Impedances per Compression Level

f (MHz)		Z_{source} Ω	Z_{load} Ω
2110	P1dB	3.50 - j7.47	1.65 - j3.64
2140	P1dB	4.21 - j7.53	1.57 - j3.70
2170	P1dB	6.39 - j8.09	1.66 - j3.68

Figure 10. Pulsed CW Output Power versus Input Power @ 28 V

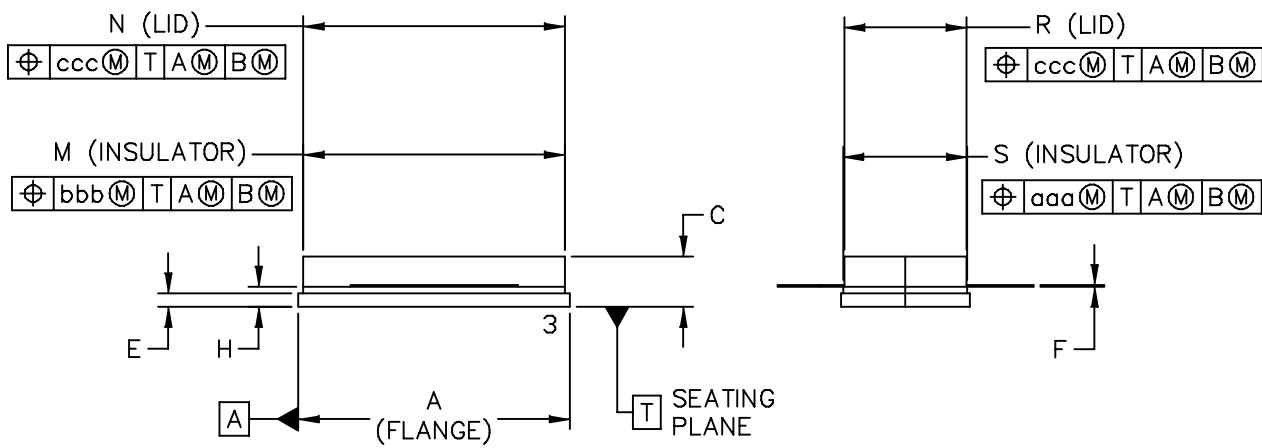
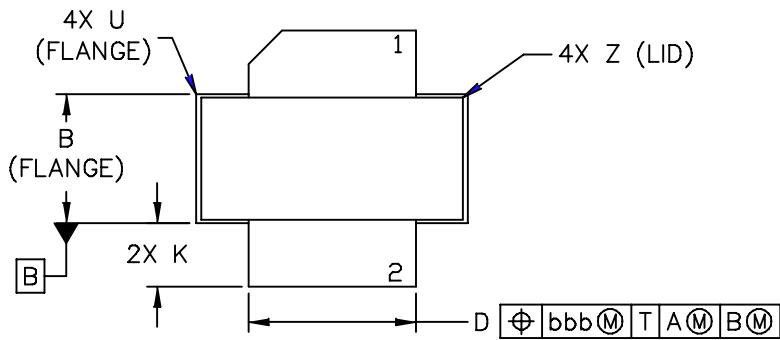
PACKAGE DIMENSIONS



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MRF8S21100HR3 MRF8S21100HSR3

RF Device Data
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MRF8S21100HR3 MRF8S21100HSR3

PRODUCT DOCUMENTATION AND SOFTWARE

Refer to the following documents, tools and software to aid your design process.

Application Notes

- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

Engineering Bulletins

- EB212: Using Data Sheet Impedances for RF LDMOS Devices

Software

- Electromigration MTTF Calculator
- RF High Power Model
- .s2p File

For Software, do a Part Number search at <http://www.freescale.com>, and select the "Part Number" link. Go to the Software & Tools tab on the part's Product Summary page to download the respective tool.

R5 TAPE AND REEL OPTION

R5 Suffix = 50 Units, 56 mm Tape Width, 13 inch Reel.

The R5 tape and reel option for MRF8S21100H and MRF8S21100HS parts will be available for 2 years after release of MRF8S21100H and MRF8S21100HS. Freescale Semiconductor, Inc. reserves the right to limit the quantities that will be delivered in the R5 tape and reel option. At the end of the 2 year period customers who have purchased these devices in the R5 tape and reel option will be offered MRF8S21100H and MRF8S21100HS in the R3 tape and reel option.

REVISION HISTORY

The following table summarizes revisions to this document.

Revision	Date	Description
0	Oct. 2010	<ul style="list-style-type: none">Initial Release of Data Sheet
1	Mar. 2011	<ul style="list-style-type: none">Corrected $V_{GG(Q)}$ V_{DD} value from 30 Vdc to 28 Vdc in On Characteristics table to reflect actual test measurement condition, p. 2

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